



SNS COLLEGE OF TECHNOLOGY

(An Autonomous Institution)
COIMBATORE-35

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DEPARTMENT OF ELECTRICAL AND ELECTRONICS ENGINEERING

19EET202 / ANALOG ELECTRONICS II YEAR / III SEMESTER

UNIT-I: PN JUNCTION DEVICE

ZENER DIODE



TOPIC OUTLINE



- Introduction of Zener Diode
- Construction of Zener Diode
- Working of Zener Diode
- Application of Zener Diode
- Numerical of Zener Diode



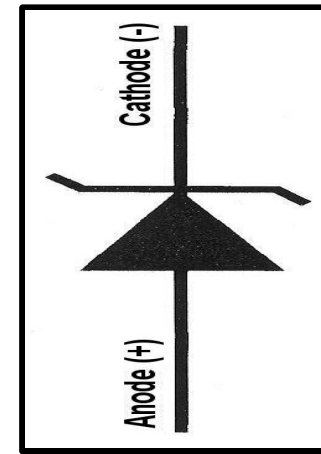
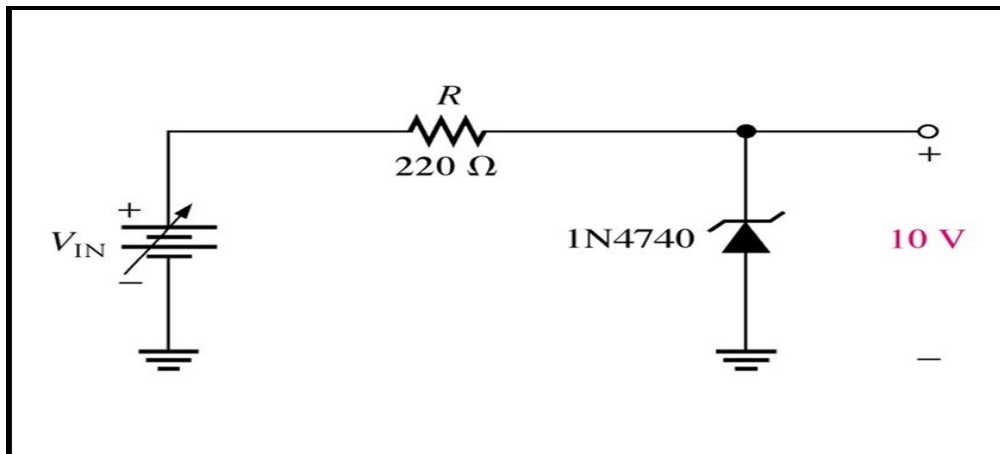


Introduction

- The **zener diode** is a silicon pn junction devices that differs from rectifier diodes because *it is designed for operation in the reverse-breakdown region.*
- The breakdown voltage of a zener diode is set by carefully controlling the level during manufacture.
- The basic function of **zener diode** is to maintain a specific voltage across it's terminals within given limits of line or load change.
- Typically it is used for providing a stable reference voltage for use in power supplies and other equipment.




zener diode



This particular zener circuit will work to maintain 10 V across the load.

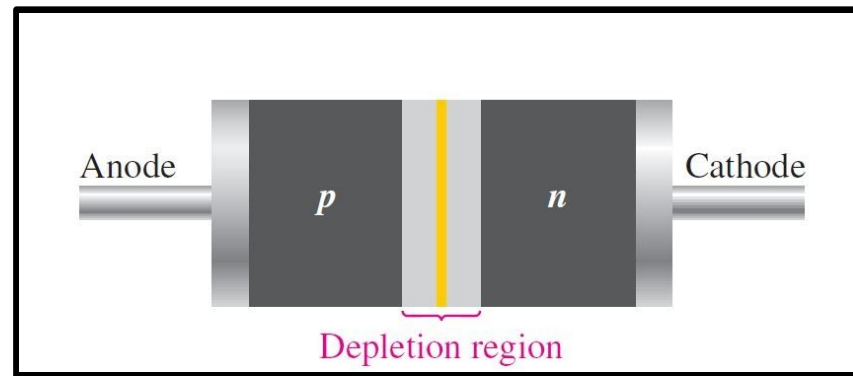
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 Zener diodes are designed to operate in reverse breakdown. Two types of reverse breakdown in a zener diode are *avalanche* and *zener*. The avalanche break down occurs in both rectifier and zener diodes at a sufficiently high reverse voltage. **Zener breakdown** occurs in a zener diode at low reverse voltages.
- A zener diode is heavily doped to reduced the breakdown voltage. This causes a very thin depletion region.
- The zener diodes breakdown characteristics are determined by the doping process
- Zeners are commercially available with voltage breakdowns of **1.8 V to 200 V**.



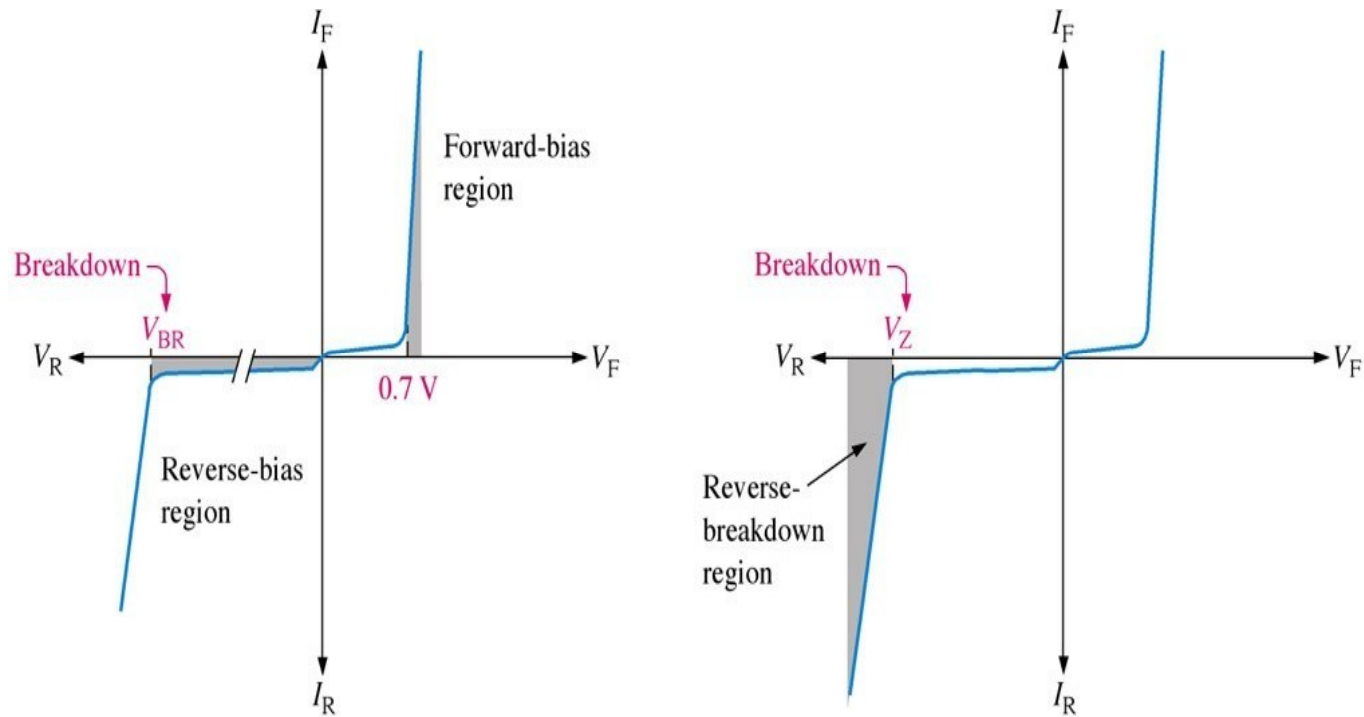
Working of Zener

- A **zener diode** is much like a normal diode. The exception being is that it is placed in the circuit in reverse bias and operates in reverse breakdown. This typical characteristic curve illustrates the operating range for a zener.
- Note that it's forward characteristics are just like a normal diode.





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(a) The normal operating regions for a rectifier diode are shown as shaded areas.

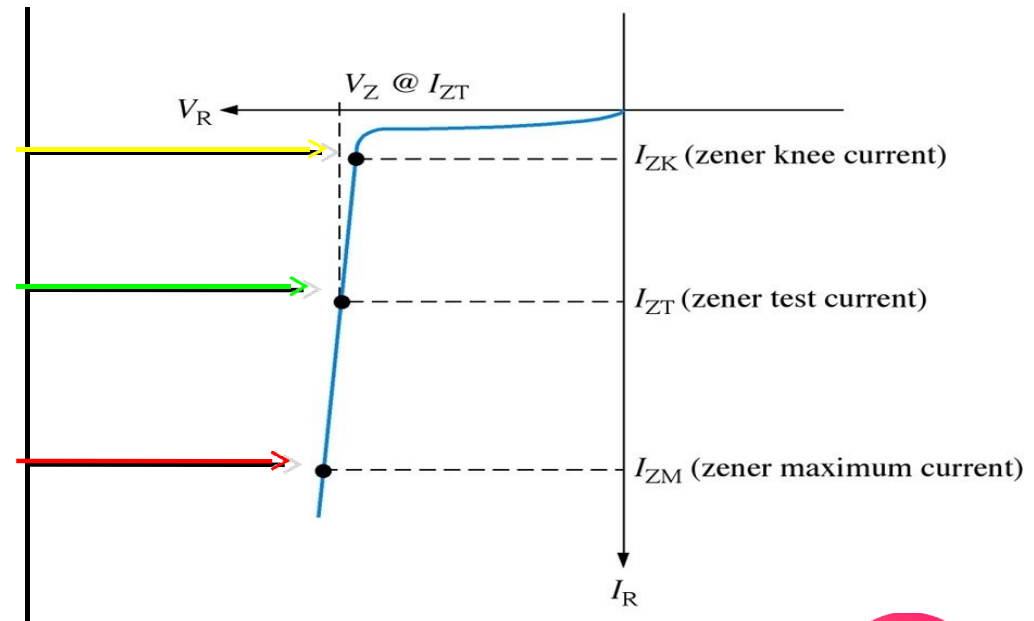
(b) The normal operating region for a zener diode is shaded.





Breakdown Characteristics

- Figure shows the reverse portion of a zener diode's characteristic curve. As the reverse voltage (V_R) is increased, the reverse current (I_R)
- remains extremely small up to the “knee” of the curve. The reverse current is also called the zener current, I_Z . At this point, the breakdown effect begins; the internal zener resistance, also called zener impedance (Z_Z), begins to decrease as reverse current increases rapidly.



ZENER BREAKDOWN



- Zener and avalanche effects are responsible for such a dramatic increase in the value of current at the breakdown voltage.
- If the impurity concentration is very high, then the width of depletion region is very less. Less width of depletion region will cause high intensity of electric field to develop in the depletion region at low voltages.





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Lets take an example to understand things clearly.

Let say the width of depletion region is 200 \AA (very small). If a reverse bias voltage of just 4 V is applied to the diode, then the electric field intensity in the depletion region will be

$$E = \frac{V}{W} = \frac{4}{200 \times 10^{-10}} = 2 \times 10^8 \text{ V/m}$$





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- Merely a voltage of 4 V is responsible to generate an electric field intensity of 2×10^8 V/m (very high intensity).
- This electric field is sufficient to rupture the bonds and separate the valence electrons from their respective nuclei.
- Large number of electrons gets separated from their atoms, resulting in sudden increase in the value of reverse current.
- This explanation was given by scientist C. E. Zener. Such diodes are called Zener diodes.
- Zener effect predominates in diodes whose breakdown voltage is below 6 V.





AVALANCHE BEAKDOWN



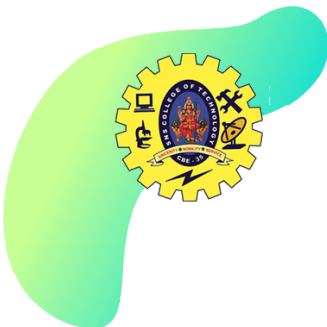
- Zener effect predominates on diodes whose breakdown voltage is below 6 V. The breakdown voltage can be obtained at a large value by reducing the concentration of impurity atom.
- We know that very little amount of current flows in the reverse biased diode. This current is due to the flow of minority charge carriers i.e., electrons in the p type semiconductor and holes in the n type semiconductor.



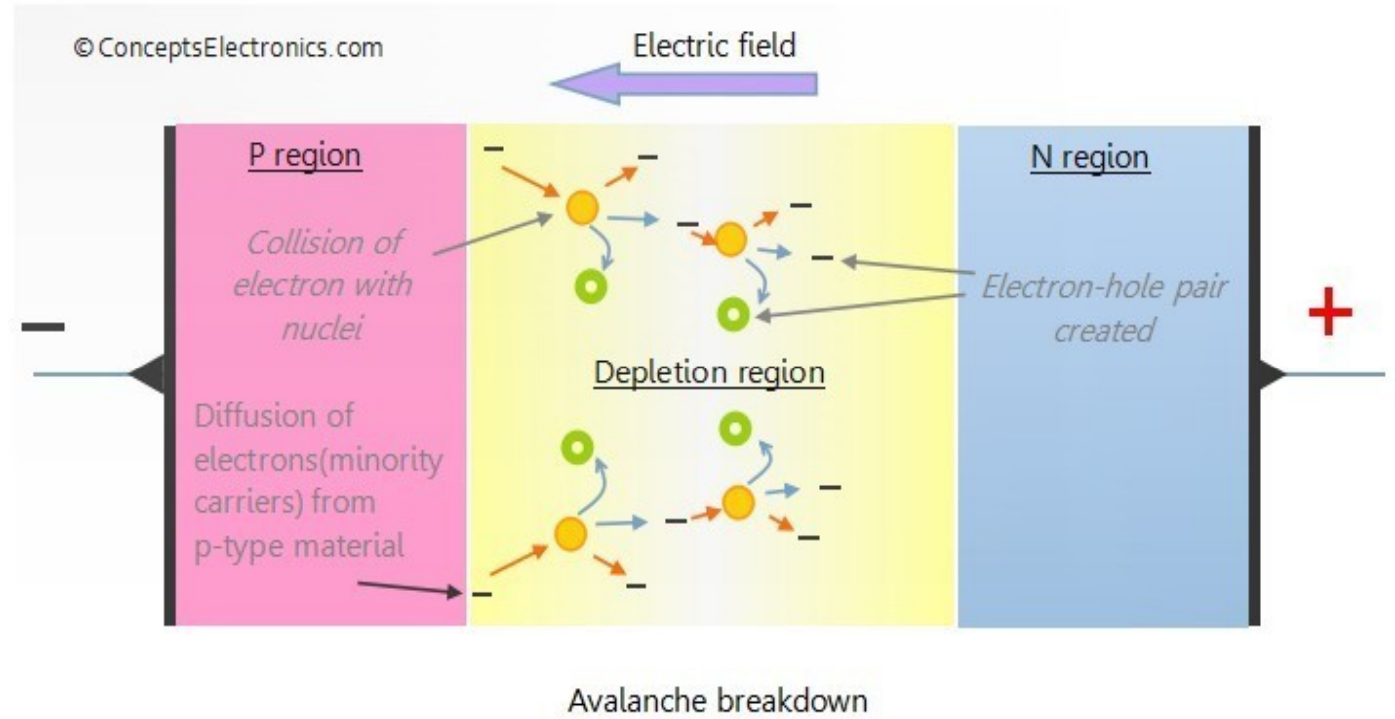
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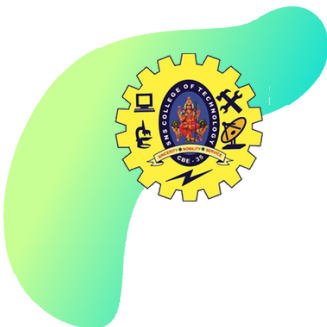


- The width of depletion region is large when the impurity concentration is less.
- When a reverse bias voltage is applied across the terminals of the diode, the electrons from the p type material and holes from the n-type materials accelerate through the depletion region.
- This results in collision of intrinsic particles (electrons and holes) with the bound electrons in the depletion region. With the increase in reverse bias voltage the acceleration of electrons and holes also increases.
- Now the intrinsic particles collide with bound electrons with enough energy to break its covalent bond and create an electron-hole pair. This is shown in the figure.

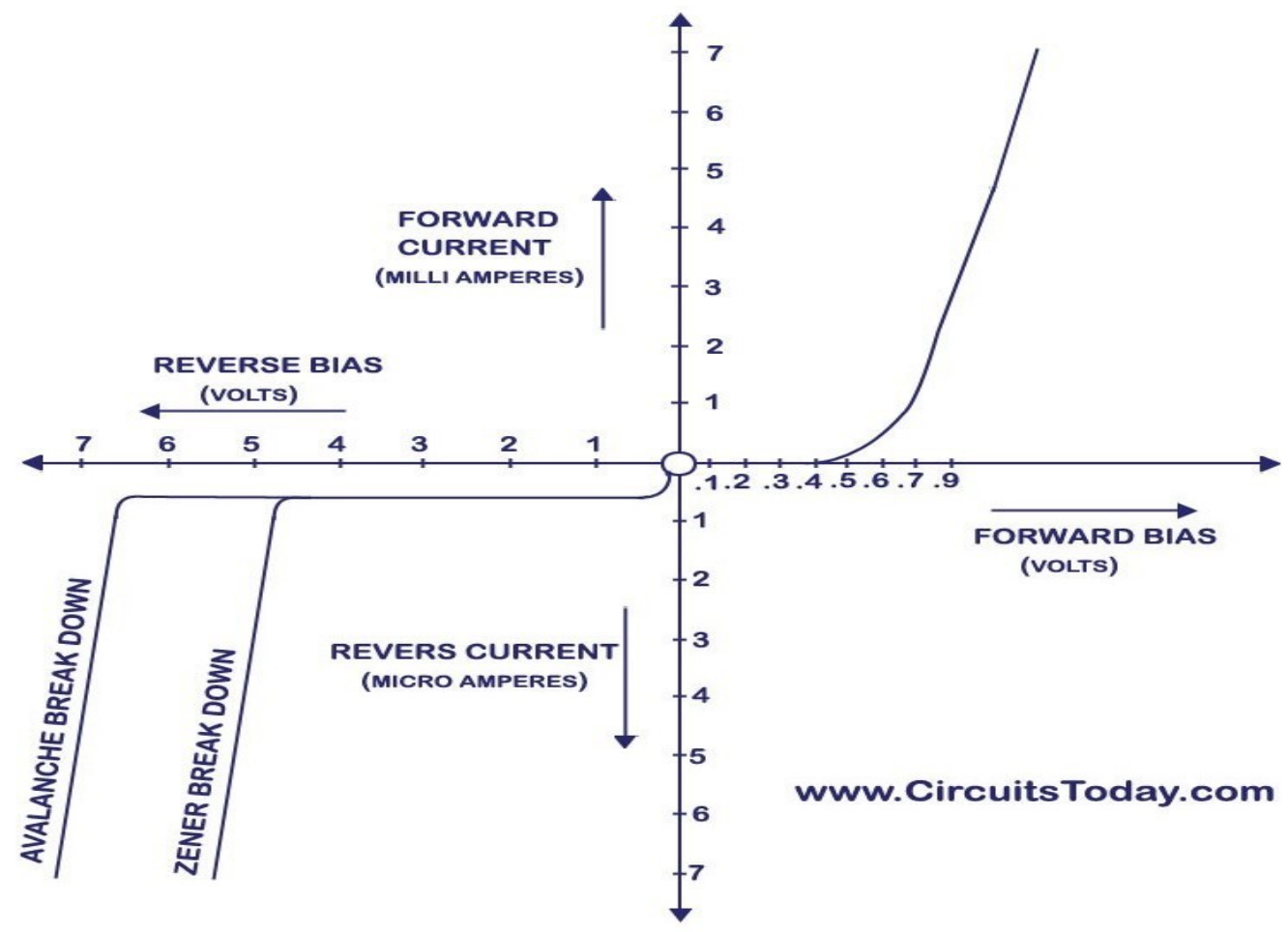


Avalanche Breakdown Mechanism





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DIFFERENCE BETWEEN ZENER AND AVALANCHE BREAKDOWN



Zener Breakdown

1. This occurs at junctions which being heavily doped have narrow depletion layers
2. This breakdown voltage sets a very strong electric field across this narrow layer.
3. Here electric field is very strong to rupture the covalent bonds thereby generating electron-hole pairs. So even a small increase in reverse voltage is capable of producing Large number of current carriers.
4. Zener diode exhibits negative temp: coefficient. I.e. breakdown voltage decreases as temperature increases.

Avalanche breakdown

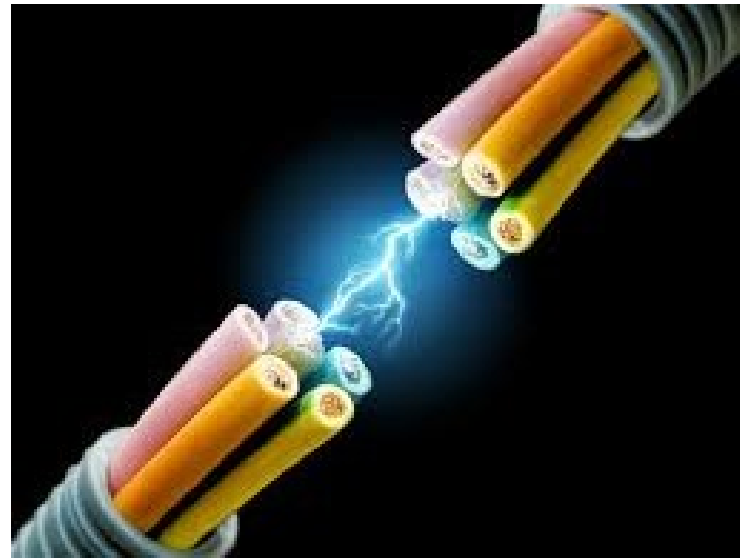


1. This occurs at junctions which being lightly doped have wide depletion layers.
2. Here electric field is not strong enough to produce Zener breakdown.
3. Her minority carriers collide with semi conductor atoms in the depletion region, which breaks the covalent bonds and electron-hole pairs are generated. Newly generated charge carriers are accelerated by the electric field which results in more collision and generates avalanche of charge carriers. This results in avalanche breakdown.
4. Avalanche diodes exhibits positive temp: coefficient. i.e breakdown voltage increases with increase in temperature.





RECAP....



...THANK YOU

